

20V, 1A, Rail-to-Rail Operational Amplifier

General Description

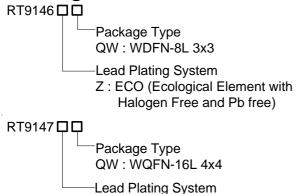
The RT9146/7 consists of a low power, high slew rate, single supply rail-to-rail input and output operational amplifier.

The RT9146 contains a single amplifier and RT9147 contains two amplifiers in one package.

The RT9146/7 has a high slew rate (35V/μs), 1A peak output current and offset voltage below 15mV. The RT9146/ 7 is ideal for Thin Film Transistor Liquid Crystal Displays (TFT LCD).

The RT9146 is available in a WDFN-8L 3x3 package. The RT9147 is available in a WQFN-16L 4x4 package. The RT9146/7 are specified for operation over the full -40°C to 85°C temperature range.

Ordering Information



Note:

Richtek products are:

▶ RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.

Z: ECO (Ecological Element with

Halogen Free and Pb free)

▶ Suitable for use in SnPb or Pb-free soldering processes.

Marking Information





85: Product Code YMDNN: Date Code

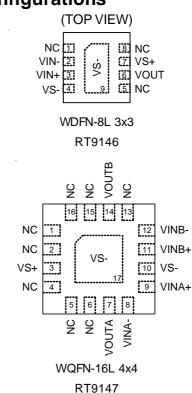
Features

- Rail-to-Rail Output Swing
- Supply Voltage: 6V to 20V
- Peak Output Current: 1A
- High Slew Rate: 35V/μs
- Unity Gain Stable
- RoHS Compliant and Halogen Free

Applications

- TFT LCD Panels
- Notebook Computers
- Monitors
- LCDTVs

Pin Configurations



RT9147ZQW

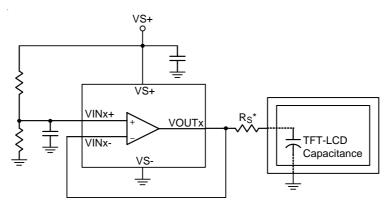


43: Product Code YMDNN: Date Code

Copyright ©2012 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.



Typical Application Circuit



 $^{^{\}star}$: R_S may be needed for some applications.

Functional Pin Description

RT9146

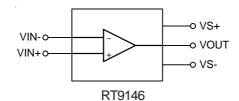
Pin No.	Pin Name	Pin Function
1, 5, 8	NC	No Internal Connection.
2	VIN-	Negative Input.
3	VIN+	Positive Input.
4, 9 (Exposed Pad)	VS-	Negative Supply Input. The exposed pad must be soldered to a large PCB and connected to VS- for maximum power dissipation.
6	VOUT	Output.
7	VS+	Positive Supply Input. Bypass VS+ to VS- with a $0.1\mu F$ capacitor as close placed as possible to the device.

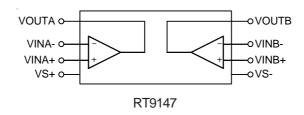
RT9147

Pin No.	Pin Name	Pin Function
1, 2, 4, 5, 6, 13, 15, 16	NC	No Internal Connection.
3	VS+	Positive Supply Input. Bypass VS+ to VS- with a $0.1\mu F$ capacitor as close placed as possible to the device.
7	VOUTA	Output of Amplifier A.
8	VINA-	Positive Input of Amplifier A.
9	VINA+	Negative Input of Amplifier A.
10, 17 (Exposed Pad)	VS-	Negative Supply Input. The exposed pad must be soldered to a large PCB and connected to VS– for maximum power dissipation.
11	VINB+	Positive Input of Amplifier B.
12	VINB-	Negative Input of Amplifier B.
14	VOUTB	Output of Amplifier B.



Function Block Diagram







Absolute Maximum Ratings (Note 1)

• Supply Voltage, (VS+ to VS-)	24V
• VINx+, VINx- to VS	
• VINx+ to VINx	±5V
 Power Dissipation, P_D @ T_A = 25°C 	
WDFN-8L 3x3	1.429W
WQFN-16L 4x4	1.852W
Package Thermal Resistance (Note 2)	
WDFN-8L 3x3, θ_{JA}	70°C/W
WDFN-8L 3x3, θ_{JC}	8.2°C/W
WQFN-16L 4x4, θ_{JA}	54°C/W
WQFN-16L 4x4, θ_{JC}	7°C/W
• Lead Temperature (Soldering, 10 sec.)	260°C
• Junction Temperature	150°C
Storage Temperature Range	
• ESD Susceptibility (Note 3)	
HBM (Human Body Mode)	2kV
MM (Machine Mode)	200V

Recommended Operating Conditions (Note 4)

• Supply Voltage, VS- = 0V, VS+	6V to 20V
• Junction Temperature Range	–40°C to 125°C

Electrical Characteristics

 $(V_{S+} = 16V, V_{S-} = 0V, V_{INx+} = V_{OUTx} = V_{S+} / 2, T_A = 25^{\circ}C, unless otherwise specified)$

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Input Characteristics						
Input Offset Voltage	Vos	$V_{CM} = V_{S+}/2$		2	15	mV
Input Bias Current	I _B	$V_{CM} = V_{S+}/2$		2	50	nA
Load Bagulation	ΔV_{LOAD}	I _{OUTx} = 0 to -80mA		0.1		mV/mA
Load Regulation		I _{OUTx} = 0 to 80mA		-0.1		
Common Mode Input Range	CMIR		0.5		V _{S+} -0.5	V
Common Mode Rejection Ratio	CMRR	$0.5V \leq V_{OUTx} \leq V_{S+} - 0.5V$		95		dB
Open Loop Gain	A _{VOL}	$0.5V \leq V_{OUTx} \leq V_{S+} - 0.5V$		118		dB
Output Characteristics						
Output Swing Low	V _{OL}	$I_L = -50 \text{mA}$		0.6	1.5	V
Output Swing High	V _{OH}	I _L = 50mA	V _{S+} - 1.5	V _{S+} - 0.3		V
Transient Peak Output Current	I _{PK}		800	1000	1400	mA

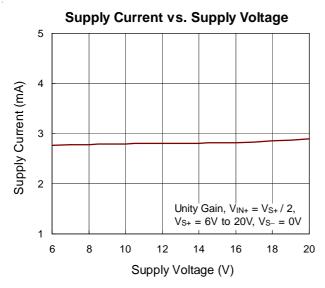


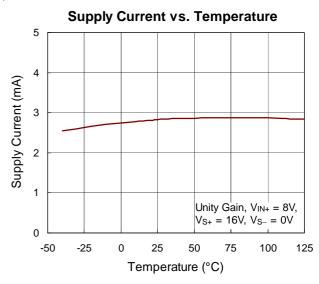
Parameter Symbo		Test Conditions	Min	Тур	Max	Unit
Power Supply						
Power Supply Rejection Ratio	PSRR	V _{S+} = 6V to 20V, V _{CM} = V _{OUTx} = V _{S+} /2		96		dB
Quiescent Current	l _{DD}	No Load		4		mA
Dynamic Performance						
Slew Rate	SR	4V step, 20% to 80%, A _V = 1		35		V/µs
Setting to $\pm 0.1\%$ (AV = 1)	t _S	$A_V = 1$, $V_{OUTx} = 2V$ step $R_L = 10k\Omega$, $C_L = 10pF$		270		ns
-3dB Bandwidth	BW	$R_L = 10k\Omega$, $C_L = 10pF$		16		MHz
Gain-Bandwidth Product	GBWP	$R_L = 10k\Omega$, $C_L = 10pF$		12		MHz
Phase Margin	PM	$R_L = 10k\Omega$, $C_L = 10pF$		50°		

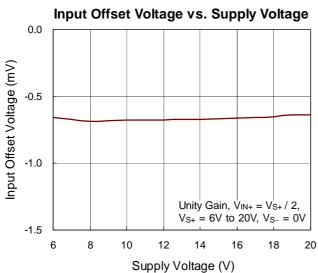
- **Note 1.** Stresses beyond those listed "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.
- Note 2. θ_{JA} is measured at $T_A = 25^{\circ}C$ on a high effective thermal conductivity four-layer test board per JEDEC 51-7. θ_{JC} is measured at the exposed pad of the package.
- Note 3. Devices are ESD sensitive. Handling precaution is recommended.
- Note 4. The device is not guaranteed to function outside its operating conditions.

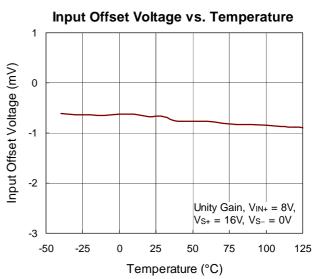


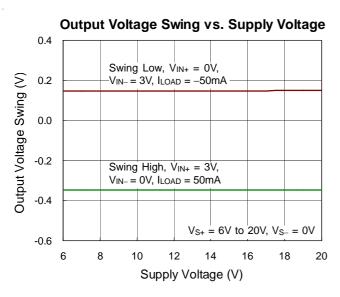
Typical Operating Characteristics

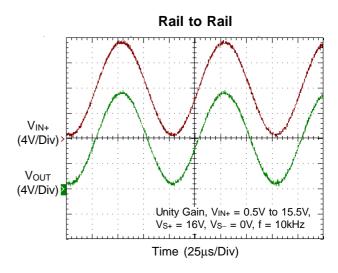






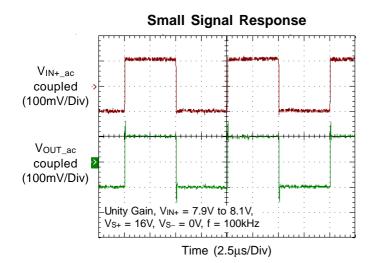


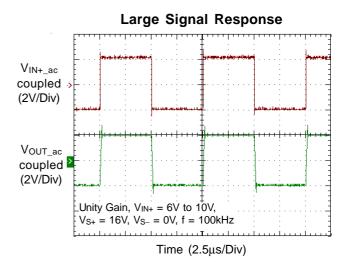


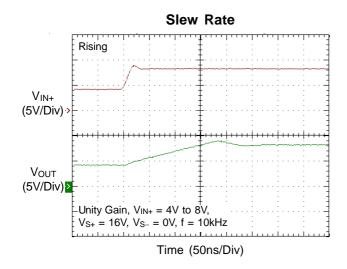


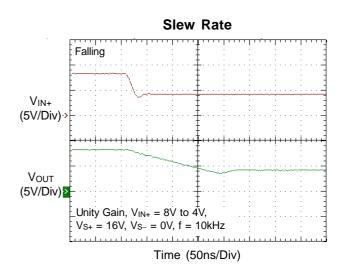
Copyright ©2012 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

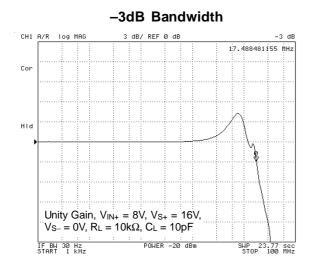


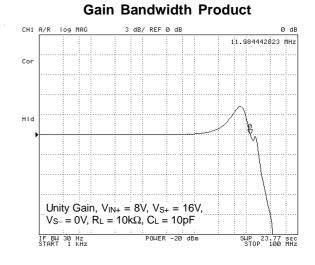












Copyright ©2012 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.



Applications Information

The RT9146/7 is a high performance operational amplifier capable of driving large loads for different applications. A high slew rates, rail-to-rail input and output capability, and low power consumption are the features which make the RT9146/7 ideal for LCD applications. The RT9146/7 also has wide bandwidth and phase margin to drive a load with $10k\Omega$ resistance and 10pF capacitance.

Operating Voltage

The RT9146/7 total supply voltage range is guaranteed from 6V to 20V. The specifications are stable over both the full supply range and operating temperatures from – 40°C to 85°C. The output swing of the RT9146/7 typically extends to within 1.5V of positive/negative supply rails with 50mA load current source/sink. Decreasing the load current will obtain an output swing even closer to the supply rails.

Short Circuit Condition

An internal short circuit protection is implemented to protect the device from output short circuit. The RT9146/7 limits the short circuit current to $\pm 1A$ if the output is directly shorted to positive/negative supply rails.

LCD Panel Applications

The RT9146/7 is mainly designed for LCD V-com buffer. The operational amplifier has 1A instantaneous source/ sink peak current.

Thermal Considerations

For continuous operation, do not exceed absolute maximum junction temperature. The maximum power dissipation depends on the thermal resistance of the IC package, PCB layout, rate of surrounding airflow, and difference between junction and ambient temperature. The maximum power dissipation can be calculated by the following formula:

$$P_{D(MAX)} = (T_{J(MAX)} - T_A) / \theta_{JA}$$

where $T_{J(MAX)}$ is the maximum junction temperature, T_A is the ambient temperature, and θ_{JA} is the junction to ambient thermal resistance.

For recommended operating condition specifications of the RT9146/7, the maximum junction temperature is 125°C and T_A is the ambient temperature. The junction to ambient thermal resistance, θ_{JA} , is layout dependent. For WDFN-8L 3x3 package, the thermal resistance, θ_{JA} , is 70°C/W on a standard JEDEC 51-7 four-layer thermal test board. For WQFN-16L 4x4 package, the thermal resistance, θ_{JA} , is 54°C/W on a standard JEDEC 51-7 four-layer thermal test board. The maximum power dissipation at T_A = 25°C can be calculated by the following formula :

$$P_{D(MAX)} = (125^{\circ}C - 25^{\circ}C) / (70^{\circ}C/W) = 1.429W$$
 for WDFN-8L 3x3 package

$$P_{D(MAX)} = (125^{\circ}C - 25^{\circ}C) / (54^{\circ}C/W) = 1.852W$$
 for

The maximum power dissipation depends on the operating ambient temperature for fixed $T_{J(MAX)}$ and thermal resistance, θ_{JA} . For the RT9146/7 packages, the derating curves in Figure 1 allows the designer to see the effect of rising ambient temperature on the maximum power dissipation.

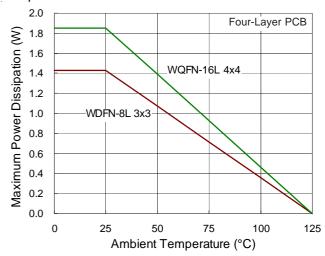


Figure 1. Derating Curves for the RT9146/7 Packages



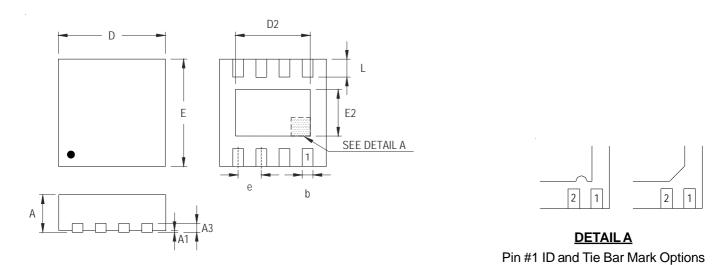
Layout Consideration

PCB layout is very important for designing power converter circuits. The following layout guidelines should be strictly followed for best performance of the RT9146/7.

- Place the power components as close to the IC as possible. The traces should be wide and short, especially for the high current loop.
- A series resistance may be needed at the output for some applications.
- Connect a 0.1μF capacitor from VINx+ to ground and place it as close to the IC as possible for better performance.
- ► The exposed pad of the chip should be connected to a large PCB plane for maximum thermal consideration.



Outline Dimension

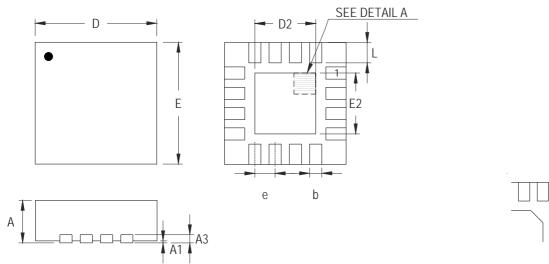


Note: The configuration of the Pin #1 identifier is optional, but must be located within the zone indicated.

Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
	Min	Max	Min	Max	
А	0.700	0.800	0.028	0.031	
A1	0.000	0.050	0.000	0.002	
A3	0.175	0.250	0.007	0.010	
b	0.200	0.300	0.008	0.012	
D	2.950	3.050	0.116	0.120	
D2	2.100	2.350	0.083	0.093	
Е	2.950	3.050	0.116	0.120	
E2	1.350	1.600	0.053	0.063	
е	0.6	550	0.0	26	
L	0.425	0.525	0.017	0.021	

W-Type 8L DFN 3x3 Package







Note: The configuration of the Pin #1 identifier is optional, but must be located within the zone indicated.

Symbol	Dimensions I	In Millimeters	Dimensions In Inches		
	Min	Max	Min	Max	
А	0.700	0.800	0.028	0.031	
A1	0.000	0.050	0.000	0.002	
A3	0.175	0.250	0.007	0.010	
b	0.250	0.380	0.010	0.015	
D	3.950	4.050	0.156	0.159	
D2	2.000	2.450	0.079	0.096	
Е	3.950	4.050	0.156	0.159	
E2	2.000	2.450	0.079	0.096	
е	0.6	550	0.0	26	
L	0.500	0.600	0.020	0.024	

W-Type 16L QFN 4x4 Package

Richtek Technology Corporation

5F, No. 20, Taiyuen Street, Chupei City Hsinchu, Taiwan, R.O.C.

Tel: (8863)5526789

Richtek products are sold by description only. Richtek reserves the right to change the circuitry and/or specifications without notice at any time. Customers should obtain the latest relevant information and data sheets before placing orders and should verify that such information is current and complete. Richtek cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Richtek product. Information furnished by Richtek is believed to be accurate and reliable. However, no responsibility is assumed by Richtek or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Richtek or its subsidiaries.

DS9146/7-02 February 2012